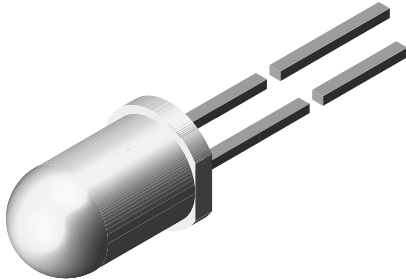




High Power Infrared Emitting Diode, 890 nm, GaAlAs / Double Hetero



94 8389



FEATURES

- Package type: leaded
- Package form: T-1 $\frac{3}{4}$
- Dimensions (in mm): \varnothing 5
- Peak wavelength: $\lambda_p = 890$ nm
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: $\varphi = \pm 22^\circ$
- Low forward voltage
- Suitable for high pulse current operation
- Good spectral matching with Si photodetectors
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Metering systems

DESCRIPTION

TSPF6200 is an infrared, 890 nm emitting diode in GaAlAs / double hetero (DH) technology with high radiant power, high speed, and with typical receiving characteristics, TSPF6200 is molded in a blue gray tinted plastic package.

PRODUCT SUMMARY

| COMPONENT | I_e (mW/sr) | φ (°) | λ_p (nm) | t_r (ns) |
|-----------|---------------|---------------|------------------|------------|
| TSPF6200 | 55 | ± 22 | 890 | 50 |

Note

- Test conditions see table "Basic Characteristics"

ORDERING INFORMATION

| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM |
|---------------|-----------|------------------------------|-------------------|
| TSPF6200 | Bulk | MOQ: 3000 pcs, 3000 pcs/bulk | T-1 $\frac{3}{4}$ |

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25$ °C, unless otherwise specified)

| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
|--|---------------------------------------|------------|-------------|------|
| Reverse voltage | | V_R | 5 | V |
| Forward current | | I_F | 100 | mA |
| Peak forward current | $t_p/T = 0.5$, $t_p = 100$ μ s | I_{FM} | 200 | mA |
| Surge forward current | $t_p = 100$ μ s | I_{FSM} | 1.5 | A |
| Power dissipation | | P_V | 170 | mW |
| Junction temperature | | T_j | 100 | °C |
| Operating temperature range | | T_{amb} | -40 to +85 | °C |
| Storage temperature range | | T_{stg} | -40 to +100 | °C |
| Soldering temperature | $t \leq 5$ s, 2 mm from case | T_{sd} | 260 | °C |
| Thermal resistance junction to ambient | J-STD-051, leads 7 mm soldered on PCB | R_{thJA} | 230 | K/W |

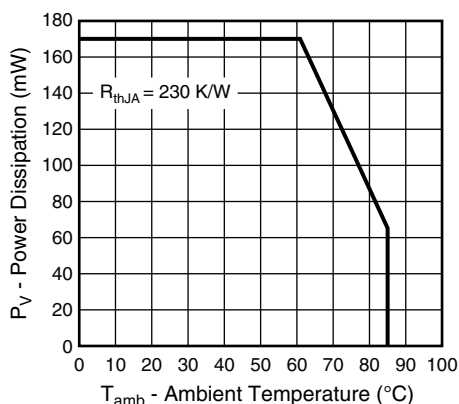


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

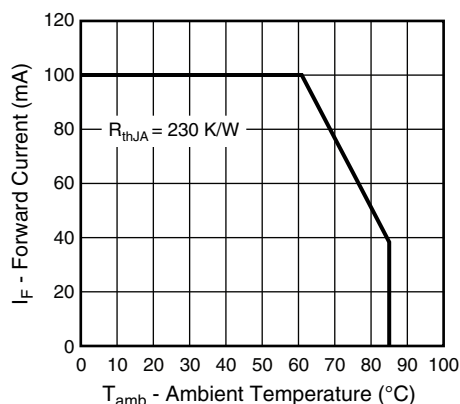


Fig. 2 - Forward Current Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | |
|--|---|------------------|------|----------|------|---------------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | $I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$ | V_F | - | 1.42 | 1.7 | V |
| | $I_F = 1\text{ A}$, $t_p = 100\text{ }\mu\text{s}$ | V_F | - | 3.0 | - | V |
| Temperature coefficient of V_F | $I_F = 100\text{ mA}$ | TK_{V_F} | - | -1.7 | - | mV/K |
| Reverse current | $V_R = 5\text{ V}$ | I_R | - | - | 100 | nA |
| Junction capacitance | $V_R = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$ | C_j | - | 160 | - | pF |
| Radiant intensity | $I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$ | I_e | 30 | 55 | 90 | mW/sr |
| | $I_F = 1\text{ A}$, $t_p = 100\text{ }\mu\text{s}$ | I_e | - | 520 | - | mW/sr |
| Short circuit current | $E_e = 1\text{ mW/cm}^2$, $\lambda = 870\text{ nm}$ | I_k | - | 10 | - | μA |
| Open circuit voltage | $E_e = 1\text{ mW/cm}^2$, $\lambda = 870\text{ nm}$ | V_0 | - | 1.0 | - | V |
| Reverse light current | $E_e = 1\text{ mW/cm}^2$, $\lambda = 870\text{ nm}$, $V_R = 5\text{ V}$ | I_{ra} | - | 10 | - | μA |
| Radiant power | $I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$ | ϕ_e | - | 40 | - | mW |
| Temperature coefficient of ϕ_e | $I_F = 100\text{ mA}$ | TK_{ϕ_e} | - | -0.35 | - | %/K |
| Angle of half intensity | | ϕ | - | ± 22 | - | $^{\circ}$ |
| Peak wavelength | $I_F = 100\text{ mA}$ | λ_p | 870 | 890 | 910 | nm |
| Spectral bandwidth | $I_F = 100\text{ mA}$ | $\Delta\lambda$ | - | 40 | - | nm |
| Temperature coefficient of λ_p | $I_F = 100\text{ mA}$ | TK_{λ_p} | - | 0.25 | - | nm/K |
| Rise time | $I_F = 100\text{ mA}$ | t_r | - | 50 | - | ns |
| Fall time | $I_F = 100\text{ mA}$ | t_f | - | 50 | - | ns |



BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

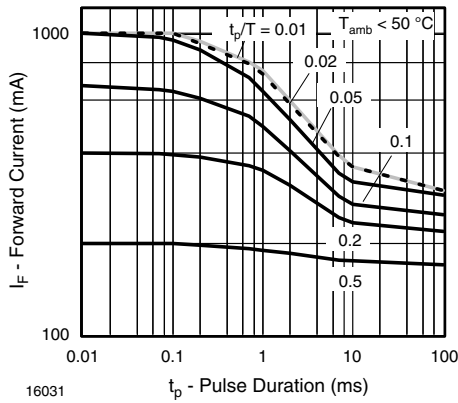


Fig. 3 - Pulse Forward Current vs. Pulse Duration

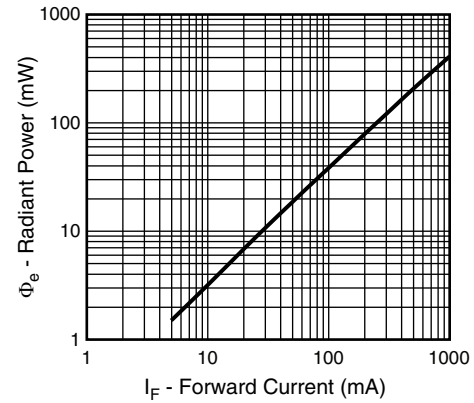


Fig. 6 - Radiant Power vs. Forward Current

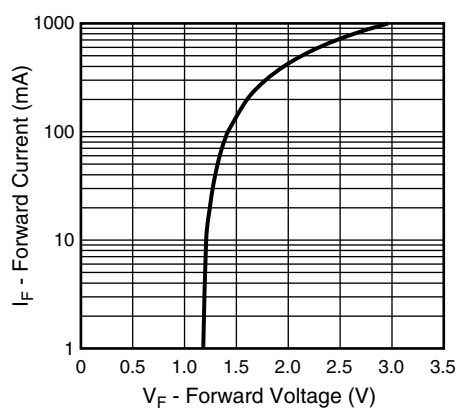


Fig. 4 - Forward Current vs. Forward Voltage

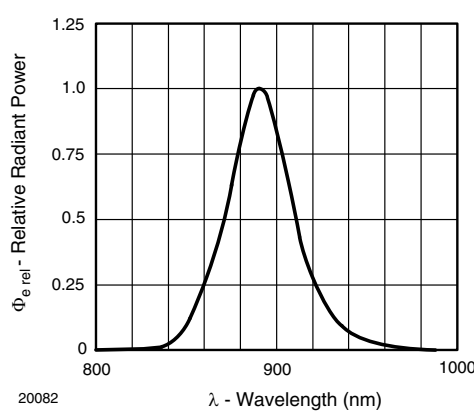


Fig. 7 - Relative Radiant Intensity / Power vs. Wavelength

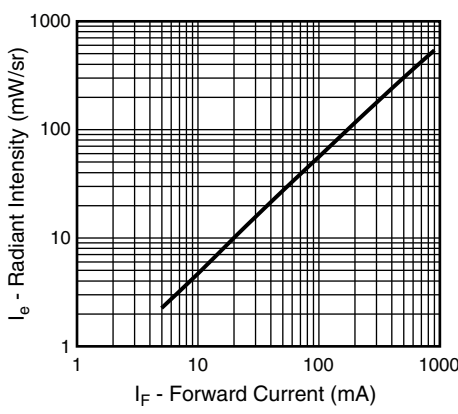


Fig. 5 - Radiant Intensity vs. Forward Current

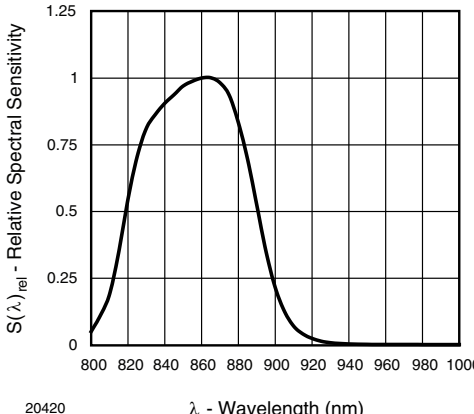


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

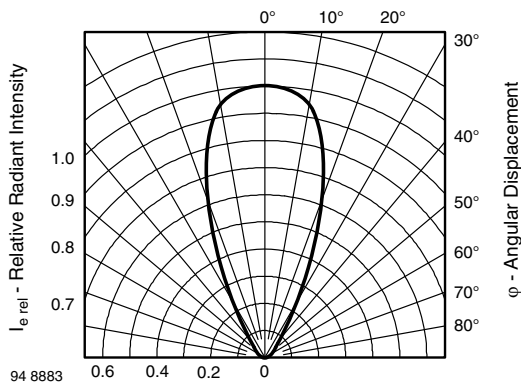
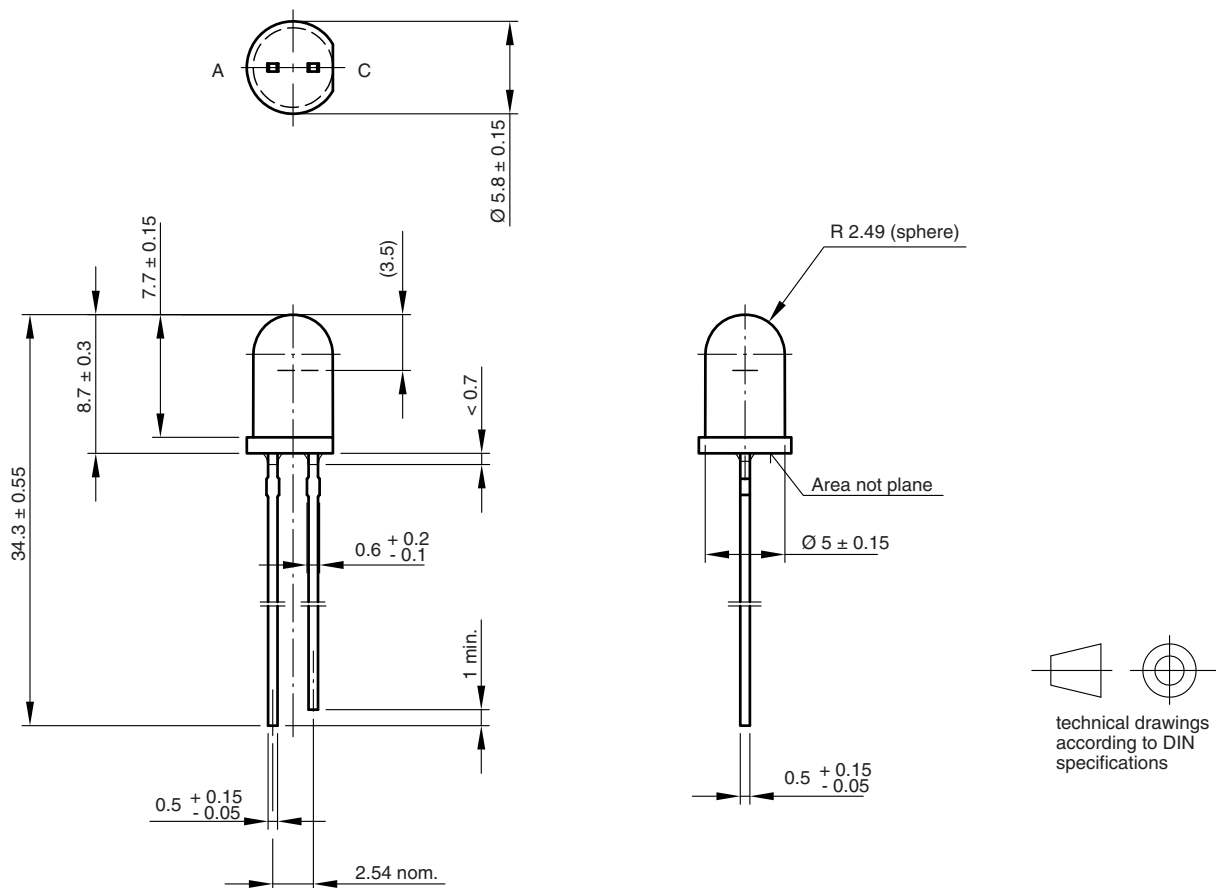


Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters



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